Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-044-3765

| Inclosure Material: | |
|---|---|
| Metal | |
| Overall Length: | |
| 0.210 inches | |
| Terminal Length: | |
| 0.500 inches | |
| Overall Diameter: | |
| 0.230 inches | |
| Joint Electronic Device Engineering Council/jede | c/case Outline Designation: |
| То-72 | |
| Component Name And Quantity: | |
| 1 transistor and 1 semiconductor device diode | |
| Mounting Method: | |
| Terminal | |
| Terminal Circle Diameter: | |
| 0.100 inches | |
| Features Provided: | |
| Hermetically sealed case | |
| Semiconductor Material: | |
| Silicon all semiconductor | |
| Voltage Rating In Volts Per Characteristic: | |
| 20.0 drain to source voltage single transistor and 25 | 5.0 drain to substrate voltage single transistor and 25.0 source to substrate voltage |
| single transistor and 30.0 gate to source voltage sin | gle transistor |
| Terminal Type And Quantity: | |
| 4 uninsulated wire lead | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |